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INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)				Complete if Known		
				Application Number	10/696,545	
				Filing Date	October 29, 2003	
				First Named Inventor	Xunming Deng	
				Group Art Unit		
·	-			Examiner Name		
Sheet	1	of	1	Attorney Docket Number	03026/PHSY00402	

Examiner Initials	Cite No.'	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	т
/JB/		PRATIMA AGARWAL*, H. POVOLNY, S. HAN and X. DENG; Study of a-SiGe:H Films and n-I-p Devices used in High Efficiency Triple Junction Solar Cells; J. of Non-Cystalline Solids (2002) Vol. 299-302 pp. 1213-1218.	
	<u> </u>		\downarrow

Examiner Signature	/Jeffrey Barton/	Date Considered	11/06/2007
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^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

(Information Disclosure Statement - Section 2. FORM 1449A/PTO (PTO/SB/08A)

page of Mar.)

¹Unique citation designation number. ² Applicant is to place a check mark here if English language Translation is attached.